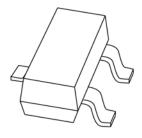


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DATA SHEET



BAW56High-speed double diode

Product specification Supersedes data of 1999 May 11 2003 Mar 25

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Product specification

High-speed double diode

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FEATURES

- · Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 450 mA.

APPLICATIONS

 High-speed switching in thick and thin-film circuits.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
BAW56	A1*

Note

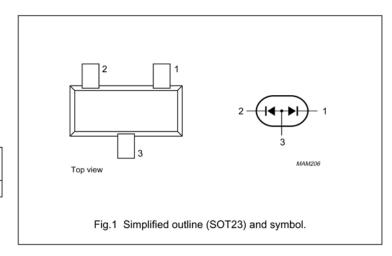
- 1. * = p: Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

DESCRIPTION

The BAW56 consists of two high-speed switching diodes with common anodes, fabricated in planar technology, and encapsulated in a small SOT23 plastic SMD package.

PINNING

PIN	DESCRIPTION
1	cathode (k1)
2	cathode (k2)
3	common anode





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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode			•		
V _{RRM}	repetitive peak reverse voltage		_	85	V
V _R	continuous reverse voltage		-	75	V
I _F	continuous forward current	single diode loaded; note 1; see Fig.2	-	215	mA
		double diode loaded; note 1; see Fig.2	-	125	mA
I _{FRM}	repetitive peak forward current		_	450	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	Α
		t = 1 ms	-	1	Α
		t = 1 s	-	0.5	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

Note

ELECTRICAL CHARACTERISTICS

 T_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode				•
V _F	forward voltage	see Fig.3		
		I _F = 1 mA	715	mV
		I _F = 10 mA	855	mV
		I _F = 50 mA	1	V
		I _F = 150 mA	1.25	V
I _R	reverse current	see Fig.5		
		V _R = 25 V	30	nA
		V _R = 75 V	1	μΑ
		V _R = 25 V; T _j = 150 °C	30	μΑ
		V _R = 75 V; T _j = 150 °C	50	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	2	pF
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.7	4	ns
V _{fr}	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V

^{1.} Device mounted on an FR4 printed-circuit board.



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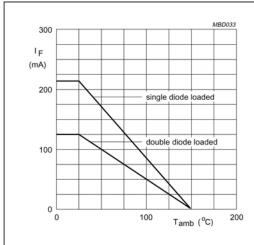
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		360	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

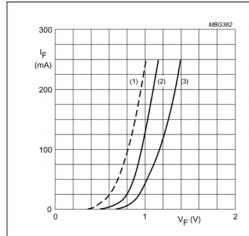
1. Device mounted on an FR4 printed-circuit board.

GRAPHICAL DATA



Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) T_i = 150 °C; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) T_i = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



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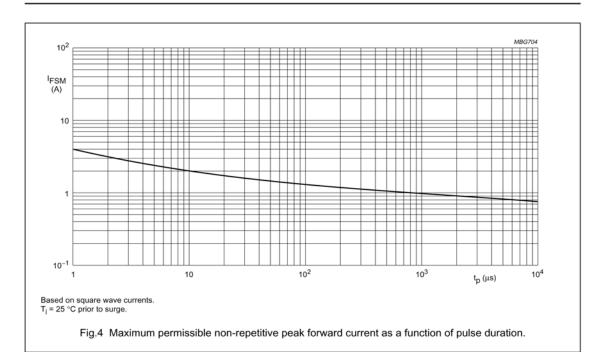
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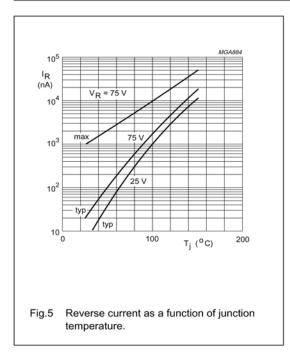
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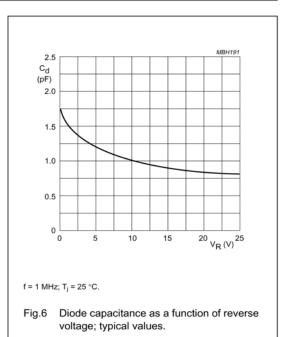
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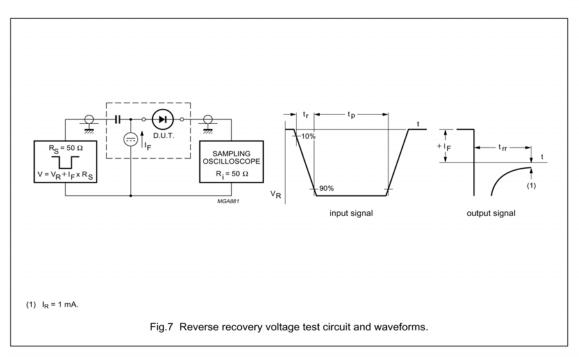
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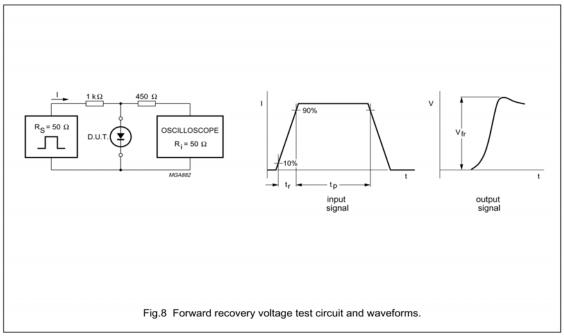
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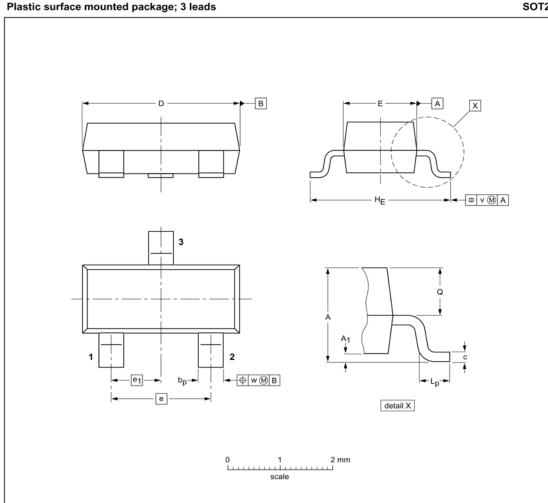
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PACKAGE OUTLINE

SOT23



DIMENSIONS	(mm are	the	original	dimensions)	

UNIT	A	A ₁ max.	bp	С	D	E	е	e ₁	HE	Lp	Q	v	w	
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1	

	REFER	EUROPEAN	ISSUE DATE		
IEC	JEDEC	EIAJ		PROJECTION	1330E DATE
	TO-236AB				97-02-28 99-09-13
	IEC	IEC JEDEC		IEC JEDEC EIAJ	IEC JEDEC EIAJ PROJECTION



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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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